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Thyristor High Voltage, Phase Control SCR, 40 A



PRIMARY CHARACTERISTICS							
I _{T(AV)} 35 A							
V _{DRM} /V _{RRM}	1200 V						
V _{TM}	1.45 V						
I _{GT}	150 mA						
TJ	-40 °C to +125 °C						
Package	TO-247AD 3L						
Circuit configuration	Single SCR						

FEATURES

- Low I_{GT} parts available
- Designed and qualified according to JEDEC[®] - JESD 47

- RoHS COMPLIANT HALOGEN FREE
- Flexible solution for reliable AC power rectification
- · Easy control peak current at charger power up to reduce passive / electromechanical components
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

• Typical usage is in input rectification crowbar (soft start) and AC switch in motor control, UPS, welding and battery charge

DESCRIPTION

The VS-40TPS12.. high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications.

AEC-Q101 qualified P/N available (VS-40TPS12LHM3, VS-40TPS12ALHM3).

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	VALUES	UNITS			
I _{T(AV)}	Sinusoidal waveform	35	Α			
I _{RMS}		55	A			
V _{RRM} /V _{DRM}		1200	V			
I _{TSM}		600	A			
V _T	40 A, T _J = 25 °C	1.45	V			
dv/dt		1000	V/µs			
di/dt		100	A/µs			
TJ		-40 to +125	°C			

VOLTAGE RATINGS							
PART NUMBER	V _{RRM} /V _{DRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA				
VS-40TPS12AL-M3	10						
VS-40TPS12L-M3	1200	1300	10				



VS-40TPS12L-M3, VS-40TPS12AL-M3

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ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	NS V/		UNITS	
Maximum average on-state current	I _{T(AV)}	T _C = 79 °C, 180° conduction half sine way	$T_{\rm C}$ = 79 °C, 180° conduction half sine wave			
Maximum continuous RMS on-state current as AC switch	I _{T(RMS)}		55	A		
Maximum peak, one-cycle	— ———————————————————————————————————	10 ms sine pulse, rated V _{RRM} applied				
non-repetitive surge current	ITSM	10 ms sine pulse, no voltage reapplied	lucitical.	600		
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	Initial $T_{,1} = T_{,1} max.$	1250	A ² s	
Maximum r-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	ij – ijiliax.	1760	A ² S	
Maximum I²√t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	oltage reapplied			
Low level value of threshold voltage	V _{T(TO)1}		1.02	V		
High level value of threshold voltage	V _{T(TO)2}	T 105 %C	1.23	l v		
Low level value of on-state slope resistance	r _{t1}	T _J = 125 °C	9.74			
High level value of on-state slope resistance	r _{t2}			7.50	mΩ	
Maximum peak on-state voltage	V _{TM}	110 A, T _J = 25 °C		1.85	V	
Maximum rate of rise of turned-on current	di/dt	T _J = 25 °C		100	A∕µs	
Maximum holding current	Ι _Η	Anode supply = 6 V, resistive load, initial T,	_J = 1 A, I _T = 25 °C	300		
Maximum latching current	١L	Anode supply = 6 V, resistive load, $T_J = 25$	5 °C	350	A	
Maximum reverse and direct lackage aureant		$T_J = 25 \text{ °C}$			mA	
Maximum reverse and direct leakage current	se and direct leakage current I_{RRM}/I_{DRM} $T_J = 125 \text{ °C}$ $V_R = \text{rated } V_{RRM}/V_{DRM}$		RM	10	1	
Maximum rate of rise of off-state voltage 40TPS12A	dv/dt	T - T maximum linear to 20 0/ 1/ - P	500	1//110		
Maximum rate of rise of off-state voltage 40TPS12	αν/αι	$T_{\rm J}$ = $T_{\rm J}$ maximum, linear to 80 % $V_{\rm DRM},R_{g}\text{-}$ k = 100 Ω			V∕µs	

TRIGGERING						
PARAMETER	SYMBOL	TEST CO	ONDITIONS	VALUES	UNITS	
Maximum peak gate power	P _{GM}			10	W	
Maximum average gate power	P _{G(AV)}			2.5	vv	
Maximum peak gate current	I _{GM}			2.5	А	
Maximum peak negative gate voltage	-V _{GM}			10	V	
		T _J = -40 °C		2.0	v	
Maximum required DC gate voltage to trigger	V _{GT}	T _J = 25 °C	 Anode supply = 6 V resistive load 	1.7		
		T _J = 125 °C	Tesistive load	1.3		
		T _J = -40 °C		200	mA	
Maximum required DC acts surrent to triager	I _{GT}	T _J = 25 °C	 Anode supply = 6 V resistive load 	150		
Maximum required DC gate current to trigger		T _J = 125 °C	Tesistive load	80		
		$T_J = 25$ °C, for 40TPS12A	40	l		
Maximum DC gate voltage not to trigger for 40TPS12	V _{GD}	T 105 °C V reted	velue	0.25	V	
Maximum DC gate current not to trigger for 40TPS12	I _{GD}	$T_J = 125 \text{ °C}, V_{DRM} = rated value$		6	mA	
Maximum DC gate voltage not to trigger for 40TPS12A	V _{GD}	T 105 °C)/ reted	0.15	V		
Maximum DC gate current not to trigger for 40TPS12A	I _{GD}	T _J = 125 °C, V _{DRM} = rated	1	mA		

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THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS		UNITS			
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +125	°C			
Maximum thermal resistance, junction to case	R _{thJC}	DC aparation	0.6				
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	40	°C/W			
Maximum thermal resistance, case to heat sink	R _{thCS}	Mounting surface, smooth and greased	0.25				
Approximate weight			6	g			
Approximate weight			0.21	oz.			
Mounting torgueminimum	۱		6 (5)	kgf · cm			
maximum	ı		12 (10)	(lbf · in)			
Marking davias		Case style TO-247AD 3L	40TPS12AL				
Marking device		Case sigle 10-247 AD 3L	40TPS12L				

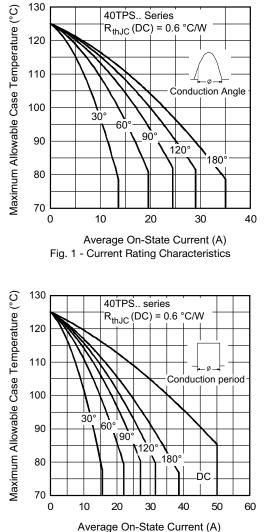


Fig. 2 - Current Rating Characteristics

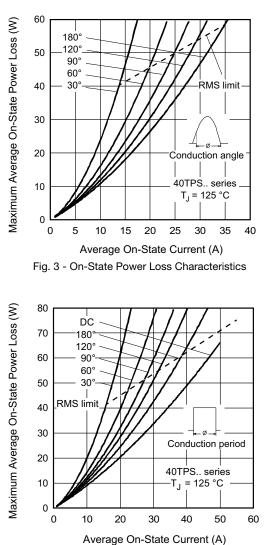
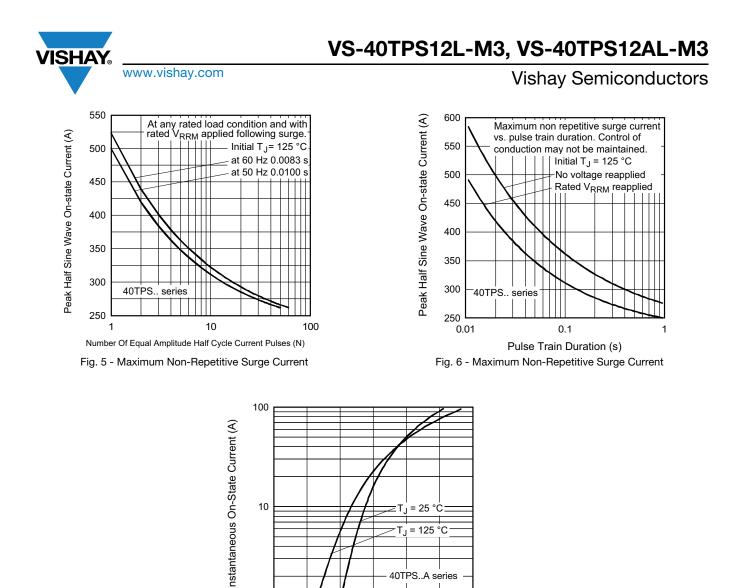
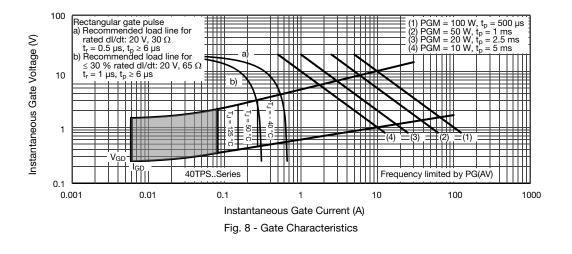


Fig. 4 - On-State Power Loss Characteristics

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1 0.5 40TPS..A series

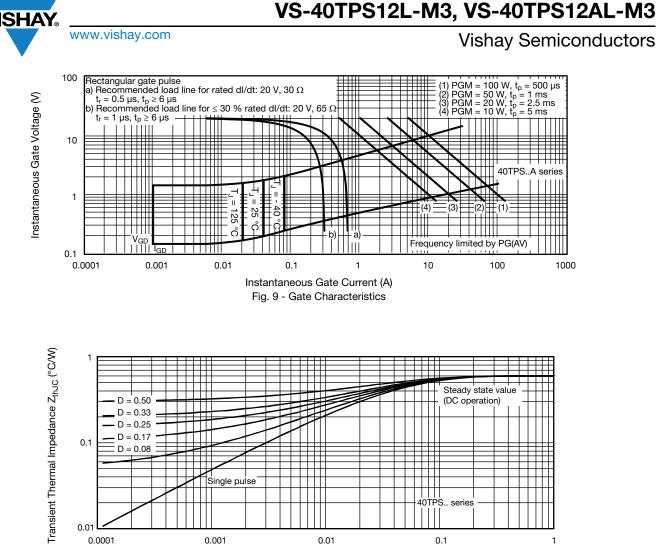
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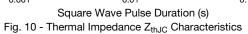
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Instantaneous On-State Voltage (V) Fig. 7 - On-State Voltage Drop Characteristics

1

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VS-40TPS12L-M3, VS-40TPS12AL-M3

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ORDERING INFORMATION TABLE

Device code	VS-	40	т	Р	s	12	A	L	-M3
		(2)	(3)	(4)	(5)	6	(7)	(8)	(9)
	<u>п</u> .	Visł	nav Sem	niconduc	ctors pro	U	\bigcirc	\bigcirc	\bigcirc
	2 -		-	ng (40 =	-	uuuu			
	3 -			iguratior	-				
			thyristo						
	4 -	Pac	kage:						
		P =	TO-247						
	5 -	Тур	e of silic	con:					
	_	S =	standar	d recove	ery rectif	fier	г		
	6 -	Volt	age rati	ngs —				12 = 12	200 V
	7 -	• A	= Low I	gt selec	tion 40 ı	mA max	kimum		
		• N	one = s	tandard	lgt seled	ction			
	8 -	L =	long lea	ds					
	9 -	Env	rironmer	ntal digit	:				
		-M3	= halog	gen-free	, RoHS-	complia	int, and	termina	tions lea

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-40TPS12AL-M3	25	500	Antistatic plastic tubes				
VS-40TPS12L-M3	25	500	Antistatic plastic tubes				

LINKS TO RELATED DOCUMENTS						
Dimensions TO-247AD 3L www.vishay.com/doc?95626						
Part marking information	TO-247AD 3L	www.vishay.com/doc?95007				



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TO-247AD 3L

DIMENSIONS in millimeters and inches



View B

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. 0.209 A 4.65 5.31 0.183 0.087 A1 2.21 2.59 0.102 A2 1.50 2.49 0.059 0.098 b 0.99 1.40 0.039 0.055 b1 0.99 1.35 0.039 0.053 b2 1.65 2.39 0.065 0.094 b3 1.65 2.34 0.065 0.092 b4 2.59 3.43 0.102 0.135 b5 2.59 3.38 0.102 0.133 с 0.38 0.89 0.015 0.035 c1 0.38 0.84 0.015 0.033 D 19.71 20.70 0.776 0.815 3 D1 13.08 -0.515 4

(2, 2_, 2, 7) (4) Section C - C, D - D, E - E

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
Е	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	5 BSC	
ØК	2.	2.54		0.010	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØР	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217	' BSC	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

⁽³⁾ Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

⁽⁵⁾ Lead finish uncontrolled in L1

(6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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 VS-2N685
 057219R

 T1190N16TOF VT
 T1220N22TOF VT
 T201N70TOH
 T700N22TOF
 T830N18TOF
 TT250N12KOF-K
 VS-110RKI40
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 NTE5442

 T2160N28TOF VT
 TT251N16KOF-K
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 TD250N16KOF-A
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 T930N36TOF VT
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 T1190N18TOF VT
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